Analog Switch

HITACHI

ADE-205-022A (Z) 2nd. Edition Aug. 1993

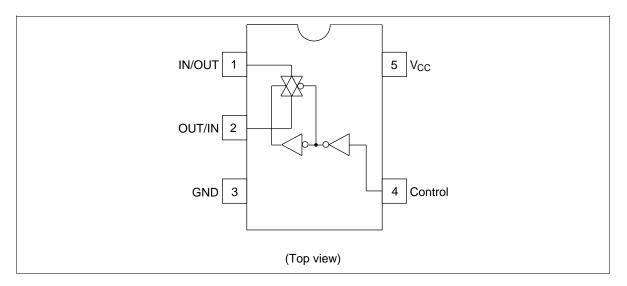
Description

The HD74UH4066 is high speed CMOS analog switch using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed. The device has low ON resistance for good transfer characteristics and can take wide range of input voltage.

Features

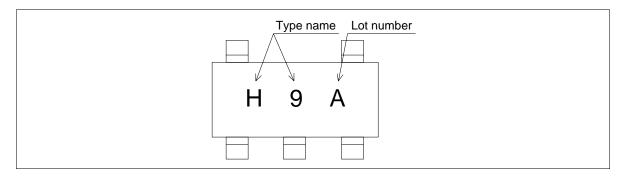
- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as hitachi uni logic series.
- Supplied on embos taping for high speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC4066 Supply voltage range: 2 to 6 V
 Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$

Pin Arrangement





Article Indication



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{cc}	-0.5 to +7.0	V
Input voltage	V _{IN}	-0.5 to V_{CC} +0.5	V
Output voltage	V _{OUT}	-0.5 to V _{cc} +0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	I _{ok}	±20	mA
Output current	I _{OUT}	±25	mA
V _{cc} /GND current	I _{CC} , I _{GND}	±25	mA
Power dissipation	P _T	200	mW
Strage temperature	Tstg	-65 to +150	°C

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	
Supply voltage	V _{cc}	2 to 6	V	
Input voltage	V _{IN}	0 to V _{cc}	V	
Output voltage	V_{OUT}	0 to V _{cc}	V	
Operating temperature	Topr	-40 to +85	°C	
Input rise/fall time	t _r , t _f	0 to 1000 ($V_{cc} = 2.0 \text{ V}$)	ns	
		0 to 500 ($V_{CC} = 4.5 \text{ V}$)		
		0 to 400 ($V_{CC} = 6.0 \text{ V}$)		

Electrical Characteristics

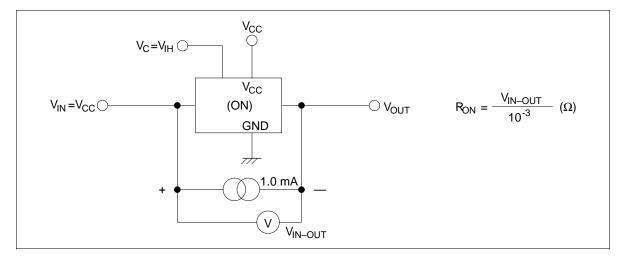
		Ta = 2	25°C		Ta = - 85°C	-40 to		Test C	Conditions
Item	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc}	_
Input voltage	V _{IH}	1.5	_	_	1.5	_	V	2.0	
		3.15	_	_	3.15	_	_	4.5	
		4.2	_	_	4.2	_	_	6.0	
	V _{IL}	_	_	0.5	_	0.5	V	2.0	
		_	_	1.35	_	1.35	=	4.5	
		_	_	1.8	_	1.8	=	6.0	
On resistance	R _{on}	_	2000	5000	_	6250	Ω	2.0	$V_{C} = V_{IH}$
		_	100	200	_	250	=	4.5	$V_{IN} = 0$ to V_{CC}
		_	60	170	_	210		6.0	$I_{IN/OUT} = 1 \text{ mA}$
Leak current	I _s (off)	_	_	±0.1	_	±1.0	μА	6.0	$\begin{aligned} &V_{\text{C}} = V_{\text{IL}} \\ &V_{\text{IN}} = V_{\text{CC}}, V_{\text{OUT}} = \text{GND} \\ &\text{or} V_{\text{IN}} = \text{GND}, V_{\text{OUT}} = V_{\text{CC}} \end{aligned}$
	I _s (on)	_	_	±0.1	_	±1.0	μΑ	6.0	$V_{C} = V_{IH}$ $V_{IN} = V_{CC}$ or GND
Input current	I _{IN}	_	_	±0.1	_	±1.0	μΑ	6.0	$V_{IN} = V_{CC}$ or GND
Operating current	I _{cc}	_	_	1.0	_	10.0	μΑ	6.0	$V_{IN} = V_{CC}$ or GND

Switching Characteristics

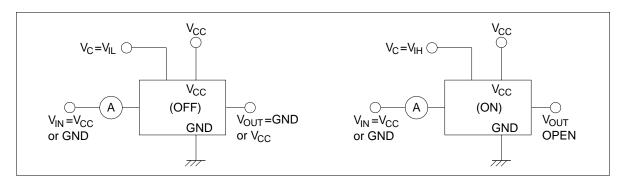
	Symbol	Ta = 25°C		Ta = −40 to 85°C			Test Conditions		
Item		Min	Тур	Max	Min	Max	Unit	V _{cc}	_
Propagation delay time	t _{PLH}	_	_	50	_	65	ns	2.0	$R_L = 10 \text{ K}\Omega$
	$t_{\tiny PHL}$	_	4	10	_	13	_	4.5	
		_	_	9	_	11		6.0	
Output enable time	t _{PZL}		_	115	_	145	ns	2.0	$R_L = 1 \text{ K}\Omega$
	$t_{\tiny PZH}$	_	10	23	_	29	_	4.5	
		_	_	20	_	25	_	6.0	
Output disable time	t _{LZ}	_	_	115	_	145	ns	2.0	$R_L = 1 \text{ K}\Omega$
	$t_{\scriptscriptstyle HZ}$	_	14	23	_	29	_	4.5	
		_	_	20	_	25	_	6.0	
Maximum control	t _{max}	_	20	_	_	_	MHz	2.0	
frequency		_	30	_	_	_	_	4.5	
		_	30	_	_	_	_	6.0	
Control input capacitance	C _{IN}	_	5	10	_	10	pF		
Switch I/O capacitance	C _{IN/OUT}	_	6	_	_	_	pF		
Feed through capacitance	C _{IN-OUT}	_	0.5	_	_	_	pF		
Power dissipation capacitance	C _{PD}	_	13		_		pF		

Test Circuit

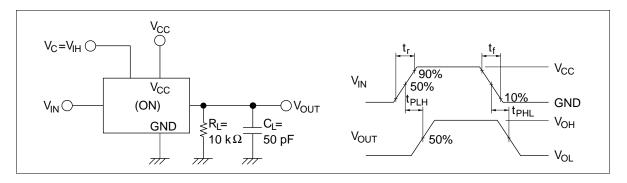
RON



$I_{S (OFF)}, I_{S (ON)}$

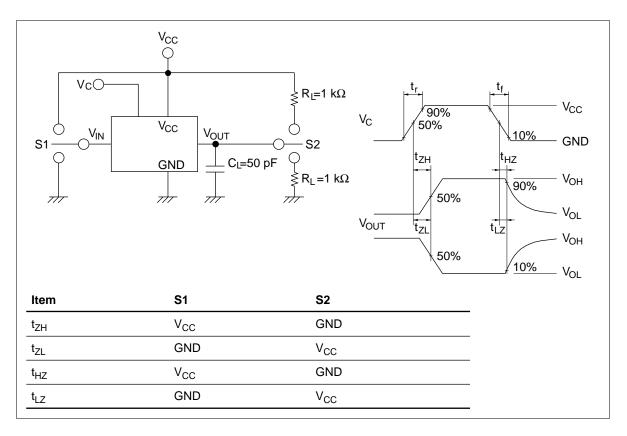


t_{PLH}, t_{PHL}

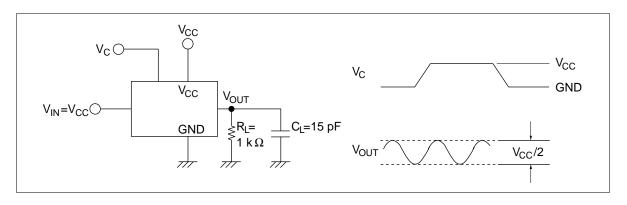


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$\mathbf{t}_{\mathrm{ZH}},\,\mathbf{t}_{\mathrm{ZL}}\,/\,\mathbf{t}_{\mathrm{HZ}},\,\mathbf{t}_{\mathrm{LZ}}$

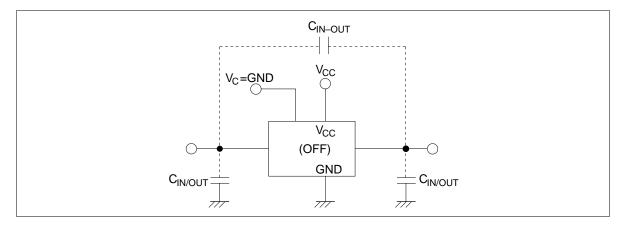


Maximum control frequency

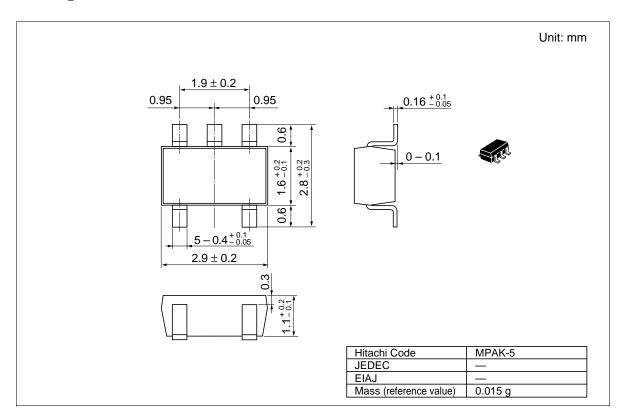


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$C_{IN/OUT}$, C_{IN-OUT}



Package Dimensions



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